Solar cells can handle energy of 70,000 suns

I like to thank TIP (one of our commentators) for reminding us of this technology. We covered it here briefly (breakthroughenergynews.com) last year. One of the most common questions raised from the BlackLight Power press release we published last week was how it is impossible to put a PV cell under so much intense light and heat. This article deals with that possibility.

A few years ago I visited a research facility in Australia that was attempting to commercialize a solar system that used a Fresnel lens to focus several hundred suns onto a triple junction cell. It worked rather well but was at the cells limits. That small cell measuring 1 cm x 2 cm was putting out over 30 watts. The big problem was heat dissipation. The following research has addressed some of these issues and actually opens up the door for one of possibilities as proposed by BlackLight Power by creating an intense light source to power solar cells. As for the rest of the claims made by BlackLight Power that is for another discussion. (article coming soon)

North Carolina State University researchers have come up with a new technique for improving the connections between stacked solar cells, which should improve the overall efficiency of solar energy devices and reduce the cost of solar energy production.

70,000 Suns

The new connections can allow these cells to operate at solar concentrations of 70,000 suns worth of energy without losing much voltage as “wasted energy” or heat.
The discovery means solar cell manufacturers can create stacked solar cells that can handle high-intensity solar energies without losing voltage at the connecting junctions, potentially improving conversion efficiency.

Stacked solar cells consist of several solar cells that are stacked on top of one another. Stacked cells are currently the most efficient cells on the market, converting up to 45 percent of the solar energy they absorb into electricity. But to be effective, solar cell designers need to ensure the connecting junctions between these stacked cells do not absorb any of the solar energy and do not siphon off the voltage the cells produce – effectively wasting that energy as heat.

“We have discovered that by inserting a very thin film of gallium arsenide into the connecting junction of stacked cells we can virtually eliminate voltage loss without blocking any of the solar energy,” says Dr. Salah Bedair, a professor of electrical engineering at NC State and senior author of a paper describing the work.

This work is important because photovoltaic energy companies are interested in using lenses to concentrate solar energy, from one sun (no lens) to 4,000 suns or more. But if the solar energy is significantly intensified – to 700 suns or more – the connecting junctions used in existing stacked cells begin losing voltage. And the more intense the solar energy, the more voltage those junctions lose – thereby reducing the conversion efficiency.

“Now we have created a connecting junction that loses almost no voltage, even when the stacked solar cell is exposed to 70,000 suns of solar energy,” Bedair says. “And that is more than sufficient for practical purposes, since concentrating lenses are unlikely to create more than 4,000 or 5,000 suns worth of energy. This discovery means that solar cell manufacturers can now create stacked cells that can handle these high-intensity solar energies without losing voltage at the connecting junctions, thus potentially improving conversion efficiency.

“This should reduce overall costs for the energy industry because, rather than creating large, expensive solar cells, you can use much smaller cells that produce just as much electricity by absorbing intensified solar energy from concentrating lenses. And concentrating lenses are relatively inexpensive,” Bedair says.

The paper, “Effect of GaAs interfacial layer on the performance of high bandgap tunnel junctions for multijunction solar cells,” was published online Sept. 5 in Applied Physics Letters. Lead author of the paper is Joshua Samberg, a Ph.D. student at NC State. Co-authors include NC State Ph.D. students Zachary Carlin, Geoff Bradshaw and Jeff Harmon; Dr. Peter Colter, a research assistant professor of electrical engineering at NC
Abstract

“Effect of GaAs interfacial layer on the performance of high bandgap tunnel junctions for multijunction solar cells”

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Abstract: The effect of the heterojunction interface on the performance of high bandgap InGa1-xP:Te/Al0.6Ga0.4As:C tunnel junctions (TJs) was investigated. The insertion of 30[Ångstrom] of GaAs:Te at the junction interface resulted in a peak current of 1000 A/cm2 and a voltage drop of ~3mV for 30 A/cm2 (2000x concentration). The presence of this GaAs interfacial layer also improved the uniformity across the wafer. Modeling results are consistent with experimental data and were used to explain the observed enhancement in TJ performance. This architecture could be used within multijunction solar cells to extend the range of usable solar concentration with minimal voltage drop.

Source: http://revolution-green.com/solar-cells-can-handle-energy-70000-suns/